

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

# **IRFR3711, IIRFR3711**

### FEATURES

- Static drain-source on-resistance: Ros(on)≤6.5mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

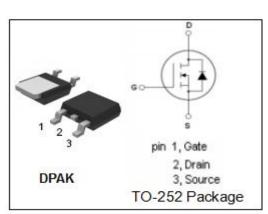
• High Frequency Buck Converters For Server Processor Power Synchronous FET

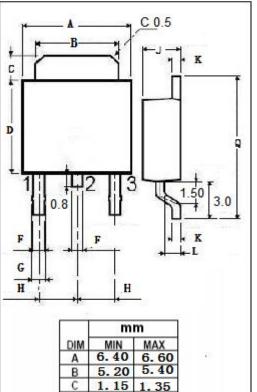
#### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	20	V				
V <sub>GS</sub>	Gate-Source Voltage	±20	V				
ID	Drain Current-Continuous	100	А				
I <sub>DM</sub>	Drain Current-Single Pulsed	440	А				
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	120	W				
Tj	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.04	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	110	℃ <b>/W</b>





5.70 6. 0.65 0.

2.10

2.10

0.40 0.90 9.90 75

2 50

10

2.40

D

G

н

0



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#### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	20			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS <b>=</b> VGS; I <sub>D</sub> =250 μ A	1.0		3.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =15A			6.5	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V			±0.2	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =16V; V <sub>GS</sub> = 0V			20	μA
V <sub>SD</sub>	Diode forward voltage	I <sub>s</sub> =30A, V <sub>GS</sub> = 0V			1.3	V

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